

# HD74LV138A

## 3-to-8-line Decoder / Demultiplexer

REJ03D0384-0100

Rev.1.00

Aug. 23, 2004

### Description

The HD74LV138A has three binary select inputs in a 16 pin package. If the device is enabled these inputs determine which one of the eight normally high outputs will go low. Two active low and one active high enables are provided to ease the cascading of decoders. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

### Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$
- All inputs  $V_{IH} (\text{Max.}) = 5.5 \text{ V} (@V_{CC} = 0 \text{ V to } 5.5 \text{ V})$
- All outputs  $V_O (\text{Max.}) = 5.5 \text{ V} (@V_{CC} = 0 \text{ V})$
- Typical  $V_{OL}$  ground bounce < 0.8 V ( $@V_{CC} = 3.3 \text{ V}, Ta = 25^\circ\text{C}$ )
- Typical  $V_{OH}$  undershoot > 2.3 V ( $@V_{CC} = 3.3 \text{ V}, Ta = 25^\circ\text{C}$ )
- High output current  $\pm 6 \text{ mA} (@V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}), \pm 12 \text{ mA} (@V_{CC} = 4.5 \text{ V to } 5.5 \text{ V})$
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV138AFPEL	SOP-16 pin (JEITA)	FP-16DAV	FP	EL (2,000 pcs/reel)
HD74LV138ATELL	TSSOP-16 pin	TTP-16DAV	T	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

### Function Table

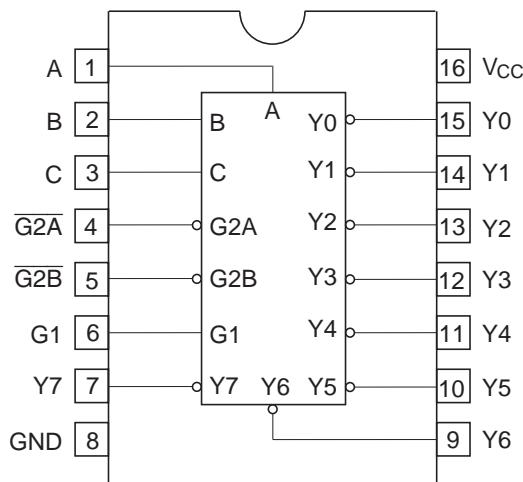
Inputs						Outputs							
Enable		Select				Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7
G1	G2A	G2B	C	B	A	H	H	H	H	H	H	H	H
X	X	H	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
L	X	X	X	X	X	H	H	H	H	H	H	H	H
H	L	L	L	L	L	L	H	H	H	H	H	H	H
H	L	L	L	L	H	H	L	H	H	H	H	H	H
H	L	L	L	H	L	H	H	L	H	H	H	H	H
H	L	L	L	H	H	H	H	H	L	H	H	H	H
H	L	L	H	L	H	H	H	H	H	L	H	H	H
H	L	L	H	H	L	H	H	H	H	H	L	H	H
H	L	L	H	H	H	H	H	H	H	H	H	H	L

H: High level

L: Low level

X: Immaterial

## Pin Arrangement



(Top view)

## Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	$V_{CC}$	-0.5 to 7.0	V	
Input voltage range <sup>*1</sup>	$V_I$	-0.5 to 7.0	V	
Output voltage range <sup>*1, 2</sup>	$V_O$	-0.5 to $V_{CC} + 0.5$	V	Output: H or L
		-0.5 to 7.0		$V_{CC}$ : OFF
Input clamp current	$I_{IK}$	-20	mA	$V_I < 0$
Output clamp current	$I_{OK}$	$\pm 50$	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	$I_O$	$\pm 25$	mA	$V_O = 0$ to $V_{CC}$
Continuous current through $V_{CC}$ or GND	$I_{CC}$ or $I_{GND}$	$\pm 50$	mA	
Maximum power dissipation at $T_a = 25^\circ\text{C}$ (in still air) <sup>*3</sup>	$P_T$	785	mW	SOP
		500		TSSOP
Storage temperature	$T_{STG}$	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. This value is limited to 5.5 V maximum.
3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

## Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V <sub>CC</sub>	2.0	5.5	V	
Input voltage range	V <sub>I</sub>	0	5.5	V	
Output voltage range	V <sub>O</sub>	0	V <sub>CC</sub>	V	
Output current	I <sub>OH</sub>	—	-50	μA	V <sub>CC</sub> = 2.0 V
		—	-2	mA	V <sub>CC</sub> = 2.3 to 2.7 V
		—	-6		V <sub>CC</sub> = 3.0 to 3.6 V
		—	-12		V <sub>CC</sub> = 4.5 to 5.5 V
	I <sub>OL</sub>	—	50	μA	V <sub>CC</sub> = 2.0 V
		—	2	mA	V <sub>CC</sub> = 2.3 to 2.7 V
		—	6		V <sub>CC</sub> = 3.0 to 3.6 V
		—	12		V <sub>CC</sub> = 4.5 to 5.5 V
Input transition rise or fall rate	Δt / Δv	0	200	ns/V	V <sub>CC</sub> = 2.3 to 2.7 V
		0	100		V <sub>CC</sub> = 3.0 to 3.6 V
		0	20		V <sub>CC</sub> = 4.5 to 5.5 V
Operating free-air temperature	T <sub>a</sub>	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

## DC Electrical Characteristics

T<sub>a</sub> = -40 to 85°C

Item	Symbol	V <sub>CC</sub> (V)*	Min	Typ	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	2.0	1.5	—	—	V	
		2.3 to 2.7	V <sub>CC</sub> × 0.7	—	—		
		3.0 to 3.6	V <sub>CC</sub> × 0.7	—	—		
		4.5 to 5.5	V <sub>CC</sub> × 0.7	—	—		
	V <sub>IL</sub>	2.0	—	—	0.5		
		2.3 to 2.7	—	—	V <sub>CC</sub> × 0.3		
		3.0 to 3.6	—	—	V <sub>CC</sub> × 0.3		
		4.5 to 5.5	—	—	V <sub>CC</sub> × 0.3		
Output voltage	V <sub>OH</sub>	Min to Max	V <sub>CC</sub> - 0.1	—	—	V	I <sub>OH</sub> = -50 μA
		2.3	2.0	—	—		I <sub>OH</sub> = -2 mA
		3.0	2.48	—	—		I <sub>OH</sub> = -6 mA
		4.5	3.8	—	—		I <sub>OH</sub> = -12 mA
	V <sub>OL</sub>	Min to Max	—	—	0.1		I <sub>OL</sub> = 50 μA
		2.3	—	—	0.4		I <sub>OL</sub> = 2 mA
		3.0	—	—	0.44		I <sub>OL</sub> = 6 mA
		4.5	—	—	0.55		I <sub>OL</sub> = 12 mA
Input current	I <sub>IN</sub>	0 to 5.5	—	—	±1	μA	V <sub>IN</sub> = 5.5 V or GND
Quiescent supply current	I <sub>CC</sub>	5.5	—	—	20	μA	V <sub>IN</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0
Output leakage current	I <sub>OFF</sub>	0	—	—	5	μA	V <sub>I</sub> or V <sub>O</sub> = 0 V to 5.5 V
Input capacitance	C <sub>IN</sub>	3.3	—	3.3	—	pF	V <sub>I</sub> = V <sub>CC</sub> or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

## Switching Characteristics

V<sub>CC</sub> = 2.5 ± 0.2 V

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)	
		Min	Typ	Max	Min	Max					
Propagation delay time	t <sub>PLH</sub> /t <sub>PHL</sub>	—	7.5	17.6	1.0	21.0	ns	C <sub>L</sub> = 15 pF	A, B or C	Y	
		—	10.0	21.4	1.0	25.0		C <sub>L</sub> = 50 pF			
		—	7.5	19.2	1.0	22.0		C <sub>L</sub> = 15 pF			
		—	10.0	22.6	1.0	26.0		C <sub>L</sub> = 50 pF			
		—	8.0	18.2	1.0	21.0		C <sub>L</sub> = 15 pF	G2A or G2B		
		—	10.5	22.0	1.0	25.0		C <sub>L</sub> = 50 pF			

V<sub>CC</sub> = 3.3 ± 0.3 V

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)	
		Min	Typ	Max	Min	Max					
Propagation delay time	t <sub>PLH</sub> /t <sub>PHL</sub>	—	5.5	11.4	1.0	13.5	ns	C <sub>L</sub> = 15 pF	A, B or C	Y	
		—	7.5	15.8	1.0	18.0		C <sub>L</sub> = 50 pF			
		—	5.5	12.8	1.0	15.0		C <sub>L</sub> = 15 pF			
		—	7.5	16.3	1.0	18.5		C <sub>L</sub> = 50 pF			
		—	6.0	11.4	1.0	13.5		C <sub>L</sub> = 15 pF	G2A or G2B		
		—	7.5	14.9	1.0	17.0		C <sub>L</sub> = 50 pF			

V<sub>CC</sub> = 5.0 ± 0.5 V

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)	
		Min	Typ	Max	Min	Max					
Propagation delay time	t <sub>PLH</sub> /t <sub>PHL</sub>	—	4.0	8.1	1.0	9.5	ns	C <sub>L</sub> = 15 pF	A, B or C	Y	
		—	5.5	10.1	1.0	11.5		C <sub>L</sub> = 50 pF			
		—	4.0	8.1	1.0	9.5		C <sub>L</sub> = 15 pF			
		—	5.5	10.1	1.0	11.5		C <sub>L</sub> = 50 pF			
		—	4.5	8.1	1.0	9.5		C <sub>L</sub> = 15 pF	G2A or G2B		
		—	5.5	10.1	1.0	11.5		C <sub>L</sub> = 50 pF			

## Operating Characteristics

C<sub>L</sub> = 50 pF

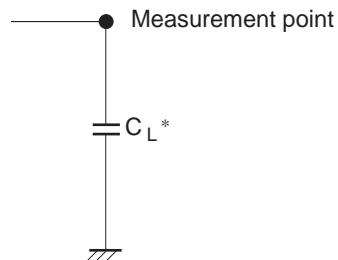
Item	Symbol	V <sub>CC</sub> (V)	Ta = 25°C			Unit	Test Conditions
			Min	Typ	Max		
Power dissipation capacitance	C <sub>PD</sub>	3.3	—	16.8	—	pF	f = 10 MHz
		5.0	—	19.1	—		

## Noise Characteristics

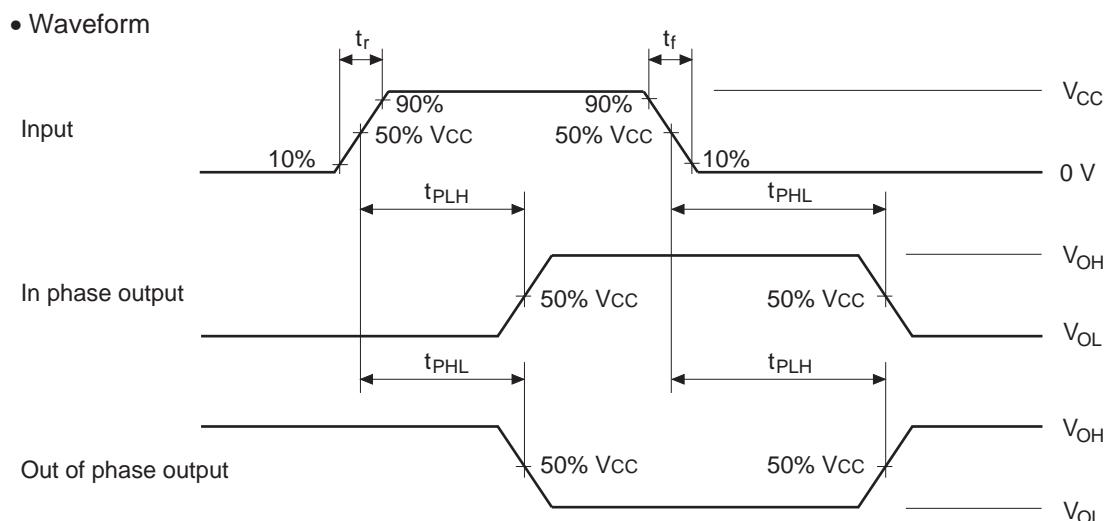
$C_L = 50 \text{ pF}$

Item	Symbol	$V_{CC} (\text{V})$	Ta = 25°C			Unit	Test Conditions
			Min	Typ	Max		
Quiet output, maximum dynamic $V_{OL}$	$V_{OL(P)}$	3.3	—	0.3	0.8	V	
Quiet output, minimum dynamic $V_{OL}$	$V_{OL(V)}$	3.3	—	-0.2	-0.8	V	
Quiet output, minimum dynamic $V_{OH}$	$V_{OH(V)}$	3.3	—	3.0	—	V	
High-level dynamic input voltage	$V_{IH(D)}$	3.3	2.31	—	—	V	
Low-level dynamic input voltage	$V_{IL(D)}$	3.3	—	—	0.99	V	

## Test Circuit

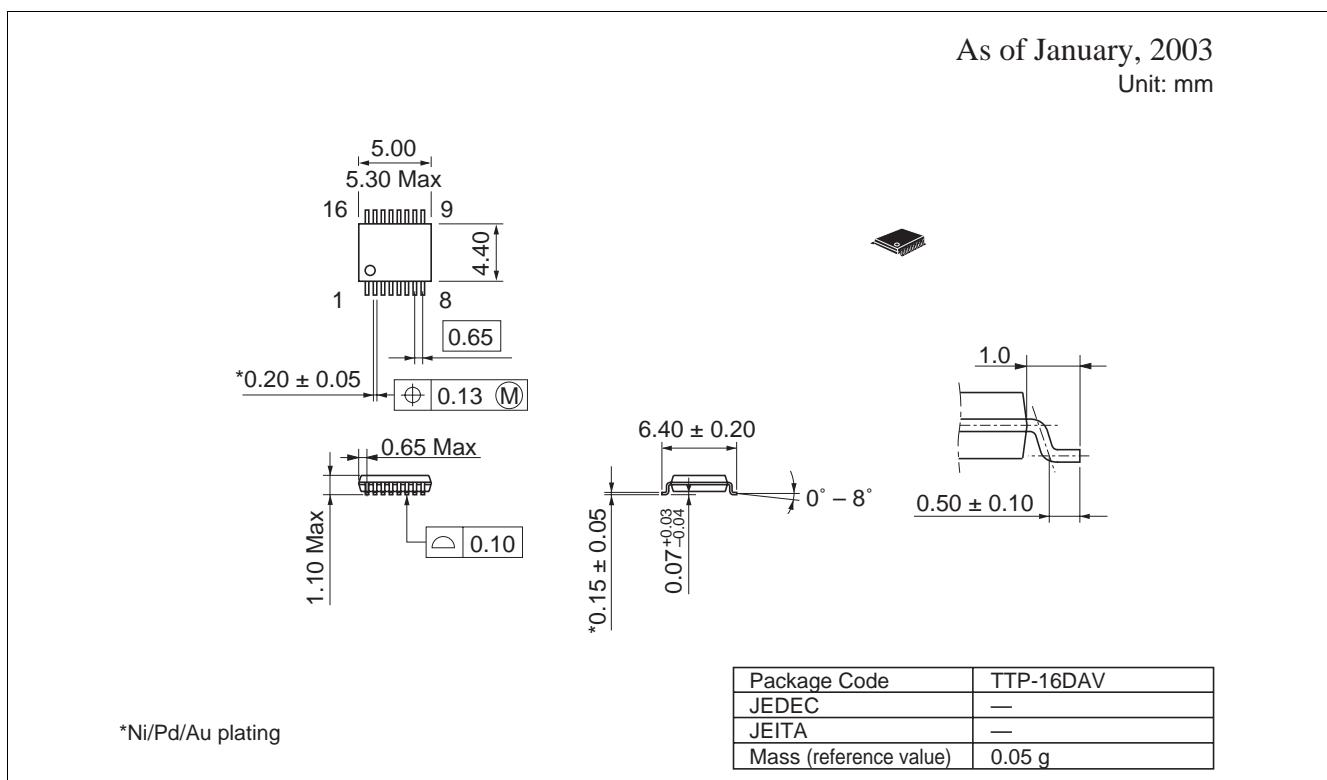
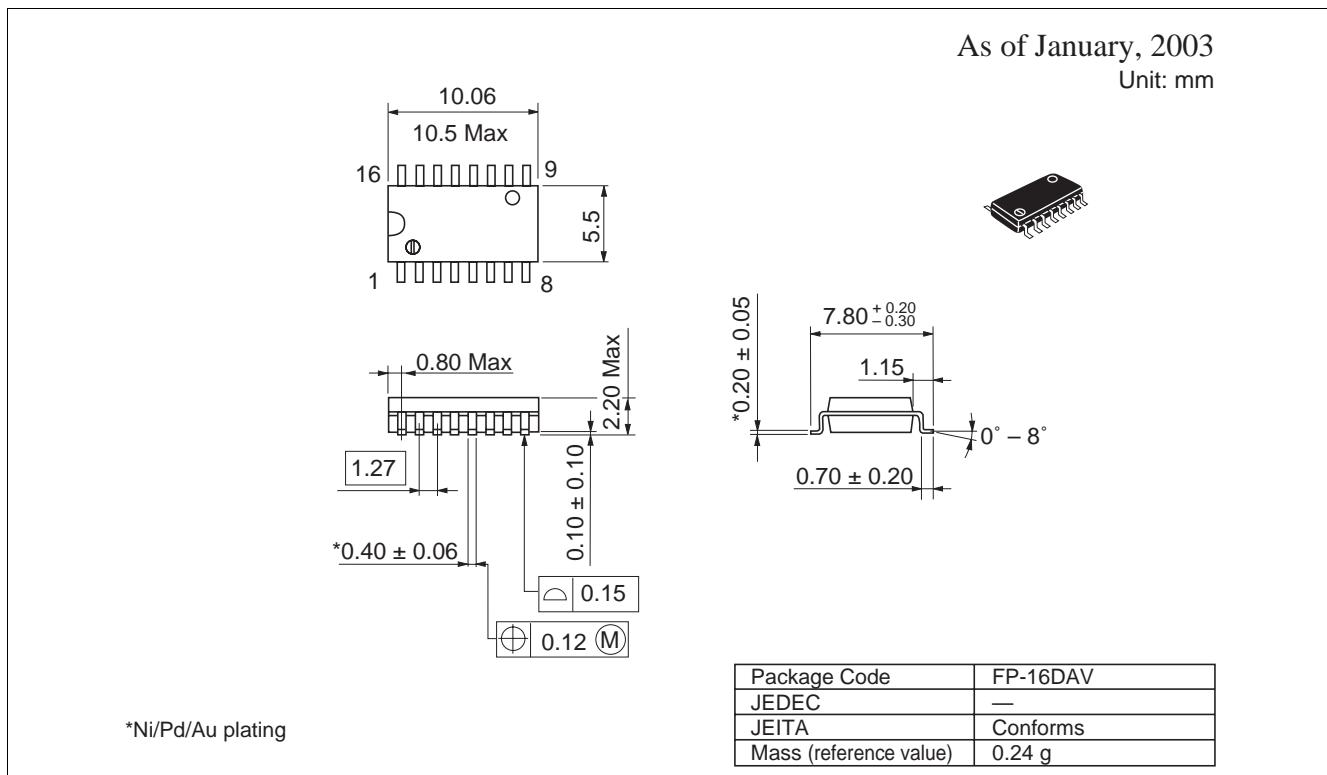


Note:  $C_L$  includes the probe and fig capacitance.



Notes: 1. Input waveform: PRR  $\leq 1 \text{ MHz}$ ,  $Z_0 = 50 \Omega$ ,  $t_r \leq 3 \text{ ns}$ ,  $t_f \leq 3 \text{ ns}$   
2. The outputs are measured one at a time with one transition per measurement.

## Package Dimensions



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